





## **Perovskite/Silicon Tandem Solar Cells and Modules**

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## **The Global Challenge**





#### Noah's ark 2050 (artist's impression, courtesy of Lisa, Emilia and David)





## PV today and tomorrow

from a niche technology to pillar of energy supply

Wafer based and thin film crystalline silicon

The working horse of PV c-Si on glass – an example from research

- High efficiency perovskite solar cells perfect partner for c-Si in tandem solar cells
- Conclusion













SOLAR

#### **GLOBAL HORIZONTAL IRRADIATION**



- Vast global potential
- Dramatic cost reductions (international bids down to 3 \$cent/kWh)
- Further strong cost reduction expected
- PV is still a new comer in the energy sector
- To impact/fight climate change huge growth of PV over decades required
- Improved and new technologies are needed see VDMA PV roadmap

## **Perspectives by New Technologies**





@ optimum working conditions for chemical processes!



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 Low cost – high efficiency mulitjunction solar cells prospects and challenges of perovskite solar cells











## Wafer Based Crystalline Silicon



## 50 years manufacturing experience

- monocrystalline
- multicrystalline

Laboratory cell efficiency:

23% various approaches
(world record lab cell: 26.6 % )

**Commercial Module Efficiencies:** 

**16 - 20%** 



#### Source: SIMTEC/ FHG ISE







# **Silicon Heterojunction Baseline**



#### 4 cm<sup>2</sup> solar cells on 5-inch Cz-Si wafer



239 cm<sup>2</sup> solar cell on 6-inch Cz-Si



IBC solar cell with photolithography



Cell area	η	V <sub>oc</sub>	j <sub>sc</sub>	FF
(cm²)	(%)	(mV)	(mA/cm²)	(%)
1 (da)	23.2	713	41.4	

Stang C., Korte L. et al., Solar RRL **1** (2017) 1700021 Stang C., Korte L. et al., to be published



**Cell area** FF **V**<sub>oc</sub> **J**<sub>SC</sub> ŋ values (cm<sup>2</sup>)(%) (mV) (mA/cm<sup>2</sup>)(%) median **22.3** 728 38.3 79.8 4 (da) busbars less **22.6** 730 best 38.2 81.0 239 (t) 5 busbars best **20.6** 722 36.0 79.3

L. Mazzarella et al., 44th IEEE PVSC, Washington 2017, submitted to J-PV A. Morales-Viches et al., 33rd EUPVSEC, Amsterdam 2017 (2.AV.3.3)

> Competence Centre Thin-Film- and Nanotechnology for Photovoltaics Berlin

## New Materials for c-Si: Perfect Interfaces, Novel Heterojunctions



#### World record: 26,6 % a-Si:H/c-Si heterojunction back contact cell Yoshikawa et al, Nature Energy 2, 17032 (2017)



25.8% for Topcon concept Team around S. Glunz Presented at FVEE conference



20,2% with organic emitter J. Schmid et al. ISFH presented at EU-PVSEC 2016

Beyond classical doping:

## carrier selective contacts

MoOx, WOx, TiOx, organic semiconductors...

Efficient silicon solar cells with dopant-free asymmetric heterocontacts J. Bullock et al. Nature Energy 1 15031 (2016)





## **Challenges in Silicon PV Technology**



- Reduction in CO<sub>2</sub> emissions necessary
- No technology available to cut wafers << 100 mm</li>
- LPC-Si as bottom up approach

# **Precursor Deposition & Crystallisation**



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#### high rate evaporation (PVD) PECVD







T. Sontheimer et al. Adv. Materials Interfaces, (2014) proof of principle

### and subsequent crystallization





D. Amkreutz et al. Prog. Photovolt. Res. Appl. 19, 937 (2011)

J. Dore et al., IEEE Journal of Photovoltaics 4, 33 (2014)



## **General Properties**



- Wafer equivalent morphology
- Low oxygen concentration (10<sup>18</sup>cm<sup>-3</sup>)
- Low carbon concentration (10<sup>17</sup>cm<sup>-3</sup>)
- High carrier mobilitiy
- Glass:silicon bond
- Fast & scaleable process

J. Haschke, D. Amkreutz, B. R., Japanese Journal of Applied Physics 55, 2016









Process	Wafer Si	c-Si on glass
energy	120 μm	20 μm
$\Sigma$ (MJ/m <sup>2</sup> )	134	37

- Material Quality approaching multi c-Si
- 16 % efficiency on very small areas
- "Between" wafer & thin film technology

Thin Si remains an important challenge for reduction of costs/energy demand



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## **Perovskite the "Hype Material"**





http://www.med.upenn.edu /chbr/documents/tr\_scienti fic\_minds\_online\_final.pdf

# SCIENTISTS WITH MULTIPLE HOT PAPERS



FIELD

Genomics

19



#### Christopher J. Murray



#### Gad Getz









S. Albrecht & B. Rech, Nat. Energy 2017

- Multi-junction PV (tandem/triple) can provide efficiencies surpassing todays limits.
- New material class of metal-halide perovskites provides a unique opportunity

**Applications beyond PV:** conversion of solar energy into chemicals, Lasers, LEDs and other optoelectronic devices

## **Perovskite Based Solar Cells**





Metal-organic perovskites showed that there are **surprising** options for **new materials**!

## **Opportunities & Challenges**





More knowledge driven development possible?

#### c-Si / Perovskite Tandem Cells Zentrum Berlin Perovskite c-Si c-Si 1.8 1.8 1.6 1.6 thermalization ~ 35% thermalization <20% Irradiance [W/(m<sup>2</sup>nm)] Irradiance [W/(m<sup>2</sup>nm)] 1.4 1.4 1.2 1.2 1.0-1.0 0.8-0.8 below below

0.6 0.4

0.2

0.0

2000

usable

energy

500

Wavelength [nm] High loss from thermalization

band-gap 20%

1500

High energy photons are absorbed by perovskite - converted at a high voltage

band-gap 20%

1500

2000

- reduced losses from thermalization

1000

Wavelength [nm]

- Infrared photons are transmitted into c-Si
  - cover a wide spectral range of absorption

0.6

0.4

0.2

0.0

usable

energy

500

1000



Efficiency: 19.9 %

- Flat Si heterojunction no texture!
- ITO as recombination layer
- MoO<sub>3</sub> between spiro-OMeTAD and top ITO
- Active area defined by ITO and aperture

S. Albrecht et al., Energy & Environmental Science 2016

# **Band-Gap Optimization: Cesium!**



#### SOLAR CELLS

### A mixed-cation lead mixed-halide perovskite absorber for tandem solar cells

David P. McMeekin,<sup>1</sup> Golnaz Sadoughi,<sup>1</sup> Waqaas Rehman,<sup>1</sup> Giles E. Eperon,<sup>1</sup> Michael Saliba,<sup>1</sup> Maximilian T. Hörantner,<sup>1</sup> Amir Haghighirad,<sup>1</sup> Nobuya Sakai,<sup>1</sup> Lars Korte,<sup>2</sup> Bernd Rech,<sup>2</sup> Michael B. Johnston,<sup>1</sup> Laura M. Herz,<sup>1</sup> Henry J. Snaith<sup>1\*</sup>



- Photostable band-gap
- Tunable perovskite for tandem cells



- Optimized architecture, light trapping
- Optimized Perovskite band-gap of 1.68 eV
- Potential for over 30% efficiency

Jäger, Rech, Albrecht et al., EUPVSEC 2017

Science 2016

# **Perovskite Solar Cells for Space**



Irradiated perovskite solar cells with high energy (68MeV) protons

- Perovskite solar cells are radiation hard
- Self-Healing of induced defects after Irradiation

### in cooperation with University Salerno



<sup>1</sup> F. Lang, et al., Adv. Mater. **28**, (2016)





- Long-lifetime, stable, including Pb-free alternatives
- Scalable low-cost processes for efficient devices
- Multi-junction solar cells & modules (Si/Pero, CIGS/Pero, Pero/Pero)
- Sustainability, environmental impact & implementation into energy system





Research approach along entire value chain (materials  $\rightarrow$  system integration) covering complete development cycle



## PV has emerged from a **niche** technology to a **global** industry

Wafer baser crystalline silicon PV dominates the market but is intrinsically limited in efficiency as a single junction technology.

- Energy demand for Si wafer production is high go thin!
- Multi-junction-technology

The development of new PV technologies relies on breakthroughs in **material science**, processing and device integration.

- Efficiency potential of novel hybrid materials has to be transferred into stable efficiency
- Prerequisite: Scalability of processes and equipment

### Cheap & efficient & stable & environmentally benign is a must!